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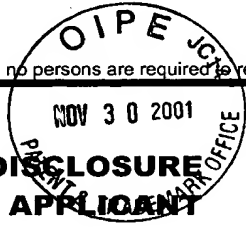
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Substitute for form 1449A/PTO				Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number		09/504,896	
		Filing Date		February 16, 2000	
		First Named Inventor		Michel Piché et al.	
		Group Art Unit		2877	
		Examiner Name		Armando Rodriguez	
Sheet	2	of	3	Attorney Docket Number 6013-63us JA/mb	

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²
AR		Actively Mode-locked GaInAsP Laser with Subpicosecond Output, S.W. Corzine et al., Appl. Phys. Lett., Vol. 52, No. 5, Feb. 1, 1988, pp. 348-350.	
AR		Actively Mode-locked External-cavity Semiconductor Lasers with Transform-limited Single-pulse Output, Alan Mar et al., Optics Letters, Vol. 17, No. 12, June 15, 1992, pp. 868-870.	
AR		Non-linear Chirp Compensation in High-Power Broad-Spectrum Pulses from Single-Stripe Mode-Locked Laser Diodes, Amine Azouz et al., IEEE Journal of Selected Topics in Quantum Electronics, Vol. 1, No. 2, June 1995, pp. 577-582.	
AR		40 GHz Active Mode-locking in a 1.5µm Monolithic Extended-cavity Laser, Electronics Letters, Vol. 25, No. 10, May 11, 1989, pp. 621-622.	
AR		Picosecond Pulse Generation by Passive Mode Locking of Diode Lasers, E. P. Ippen et al., Appl. Phys. Lett. Vol. 37, No. 3, August 1, 1980, pp. 267-269.	
AR		Subpicosecond Pulses from Passively Mode-locked GaAs Buried Optical Guide Semiconductor Lasers, J. P. van der Ziel et al. Appl. Phys., Vol. 39, No. 7, October 1, 1981, pp. 525-527.	
AR		230 fs, 25 W Pulses from Conventional Mode-locked Laser Diodes with Saturable Absorber Created by Ion Implantation, Electronic Letters, Vol. 29, No. 2, January 21, 1993, pp. 160-162.	
AR		Passive Mode Locking of a Semiconductor Diode Laser, Y. Silverberg et al., Optics Letters, Vol. 9, No. 11, November 1984, pp. 507-509.	
AR		Passive Mode Locking of Buried Heterostructure Lasers with Nonuniform Current Injection, Christoph Harder et al., Appl. Phys. Lett., Vol. 42, No. 9, May 1, 1983, pp. 772-774.	
AR		Subpicosecond Monolithic Colliding-pulse Mode-locked Multiple Quantum Well Lasers, Y.K. Chen et al., Appl. Phys. Lett., Vol. 58, No. 12, March 25, 1991, pp. 1253-1255.	
AR		Colliding Pulse Mode Locking of a Semiconductor Laser in an External Ring Cavity, Appl. Phys. Lett. Vol. 62, No. 10, March 8, 1993, pp. 1053-1055.	

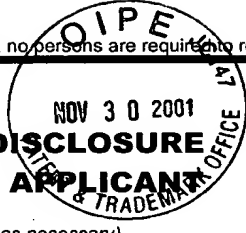
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AK		Transform-limited 1.4 ps Optical Pulses from a Monolithic Colliding-pulse Mode-locked Quantum Well Laser, M.C. Wu et al., Appl. Phys. Lett. Vol. 57, No. 8, August 20, 1990, pp. 759-761.	
AR		200-fs Optical Pulse Generation and Intracavity Pulse Evolution in a Hybrid Mode-locked Semiconductor Diode-laser/amplifier System, Peter J. Delfyett et al., Optics Letters, Vol. 17, No. 9, May 1, 1992, pp. 670-672.	
AR		The Soliton Laser, L.F. Mollenauer et al., Optics Letters, Vol. 9, No. 1, January 1984, pp.13-15.	
AR		60-fsec Pulse Generation from a Self-mode-locked Ti:sapphire Laser, D.E. Spence et al., Optics Letters, Vol. 16, No. 1, January 1, 1991, pp. 42-44.	
AR		Coupled-Cavity Passive Mode-Locked Injection Laser, E. M. Dianov et al., IEEE Photonics Technology Letters, Vol. 3, No. 6, June 1991, pp. 499-500.	
AR		Optical Pulse Generation with a Semiconductor Laser in a Coupled-Cavity Configuration, W.H. Loh et al., Pure Appl. Opt. 1, 1992, pp. 181-184.	

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